

DECLARATION AND POWER OF ATTORNEY

As a below named inventor, I hereby declare:

the specification of which (check one)

That my residence, post office address and citizenship are as stated below next to my name.

That I verily believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural inventors are named below) of the subject matter which is claimed and for which a patent is sought on the invention entitled:

SILICON NANOPARTICLE FIELD EFFECT TRANSISTOR AND TRANSISTOR MEMORY DEVICE

() is a	ttached hereto.					MAY 1 2	2000
App	ofiled on <u>February 2.</u> plication Serial No. Of was amended on	2000 9/496,506 (if applicable)	as			PH.	MEN SERV
	at I have reviewed and un	nderstand the cont		-identified specifica	tion, includin	ng the claims,	as amended by
•	lment referred to above.					4	1 '41
	it I acknowledge the duty Code of Federal Regulati		ation known to be	e material to patentat	oility of this a	ipplication in	accordance with
or inventor	nt I hereby claim foreign r's certificate listed below having a filing date befo	v and have also ide	ntified below any	foreign application	19 of any for for patent of	eign applicati r inventor's ce	on(s) for patent
Prior For	eign Application(s)					Priority Cla	aimed
(Number)	-	(Country)		(Day/Month/Yea	– or Filed)	() Yes	() No
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(Number)		(Country)		(Day/Month/Yea	 ır Filed)	Yes	() No
						() Yes	() No
(Number)		(Country)		(Day/Month/Yea	r Filed)		
insofar as manner pro as defined	at I hereby claim the bend the subject matter of ea ovided by the first parage in Title 37, Code of Fed or PCT international filin	ach of the claims of raph of Title 35, Un eral Regulations, §	of this application nited States Code, 1.56(a) which oc	n is not disclosed in §112, I acknowledg	the prior Unge the duty to	nited States ap disclose mate	pplication in the rial information
United St	ates Application(s)						
	426,204	10	0/25/99			nding	· ·
(Applicati	on Serial No.)	·	(Filing Date)		(Status)-(Pa	itentea, pendi	ng, abandoned)
(Applicati	on Serial No.)		(Filing Date)		(Status)-(Pa	itented, pendi	ng, abandoned)
(Applicati	on Serial No.)	 	(Filing Date)		(Status)-(Pa	itented, pendi	ng, abandoned)

That all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issuing thereon.

I hereby appoint the following attorneys and agents, with full power of substitution and revocation, to prosecute this application and to transact all business in the United States Patent and Trademark Office connected therewith and request that all correspondence and telephone calls in respect to this application be directed to GREER, BURNS & CRAIN, LTD., Suite 8660 - Sears Tower, 233 South Wacker Drive, Chicago, Illinois 60606, Telephone No. (312) 993-0080:

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•			
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joint inventor, if any:			
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Full name of additional joint inventor, if any:	Gennadiy Belompin
Inventor's signature:	Coursely Below
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Full name of additional joint inventor, if any:	
Inventor's signature:	
Date:	
Residence and Post Office Address:	
Citizenship:	
Full name of additional joint inventor, if any:	
Inventor's signature:	
Date:	
Residence and Post Office Address:	
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Applicant or Patentee: Serial or Patent No.: Filed or Issued:

For:

Munir H. Nayfeh, Joel Therrien, Gennadiy Bermoin Atty Docket No. 1201,63407

February 2, 2000

SILICON NANO
MEMORY DEVI

patent no.

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SILICON NANOPARTICLE FIELD EFFECT TRANSISTOR AND TRANSISTOR MEMORY DEVICE

VERIFIED STATEMENT (DECLARATION) CLAIMING SMALL ENTITY STATUS (37 CFR 1.9(f) AND 1.27(d) - NONPROFIT ORGANIZATION)

I hereby declare that I am an official empowered to act on behalf of the nonprofit organization identified below: NAME OF ORGANIZATION: THE BOARD OF TRUSTEES OF THE UNIVERSITY OF THE POINT OF TRUSTEES OF THE UNIVERSITY OF TRUSTEES OF TRUSTEES OF THE UNIVERSITY OF TRUSTEES OF TRUSTEES OF THE UNIVERSITY OF TRUSTEES OF TRUS ADDRESS OF ORGANIZATION: 352 Henry Administration Building, 506 S. Wright 61801 TYPE OF ORGANIZATION: MAY 1 2 2009 UNIVERSITY OR OTHER INSTITUTION OF HIGHER EDUCATION (X) TAX EXEMPT UNDER INTERNAL REVENUE SERVICE CODE (26 USC 503(a) and 501(c)) NONPROFIT SCIENTIFIC OR EDUCATION UNDER STATUTE OF STATE OF THE UNIXE) STATES OF AMERICA (NAME OF STATE (CITATION OF STATUTE WOULD QUALIFY AS TAX EXEMPT UNDER INTERNAL REVENUE SERVICE CODE (26 use 501 (a) and 501 (c)(3) IF LOCATED IN UNITED STATES OF AMERICA WOULD QUALIFY AS NON PROFIT SCIENTIFIC OR EDUCATION UNDER STATUTE OF () STATE OF THE UNITED STATES OF AMERICA IF LOCATED IN THE UNITED STATES OF AMERICA (NAME OF STATE (CITATION OF STATUTE I hereby declare that the nonprofit organization identified above qualifies as a nonprofit organization as defined in 37 CFR 1.9(e) for purposes of paying reduced fees to the United States Patent and Trademark Office with regard to the invention entitled SILICON NANOPARTICLE FIELD EFFECT TRANSISTOR AND TRANSISTOR MEMORY DEVICE by inventor(s) Munit H. Nayfeh, Joel Therrien, Gennadiy Belmoin described in: the specification filed herewith. application serial no. 09/496, 506 , filed February 2, 2000 (X)

I hereby declare that rights under contract or law have been conveyed to and remain with the nonprofit organization with regard to the above identified invention.

_, issued

If the rights held by the above-identified nonprofit organization are not exclusive, each individual, concern, or organization having rights to the invention is listed below* and no rights to the invention are held by any person, other than the inventor, who would not qualify as an independent inventor under 37 CFR 1.9(c) if that person made the invention, or by any concern which would not qualify as a small business concern under 37 CFR 1.9(d), or a nonprofit organization under 37 CFR 1.9(e). *NOTE: Separate verified statements are required from each named person, concern, or organization having rights to the invention averring to their status as small entities. (37 CFR 1.27)

NAME		
ADDRESS		
() INDIVIDUAL	() SMALL BUSINESS CONCERN	() NONPROFIT ORGANIZATION
•		
NAME		
ADDRESS		
() INDIVIDUAL	() SMALL BUSINESS CONCERN	() NONPROFIT ORGANIZATION

I acknowledge the duty to file, in this application or patent, notification of any change in status resulting in loss of entitlement to small entity status prior to paying, or at the time of paying, the earliest of the issue fee or any maintenance fee due after the date on which status as a small entity is no longer appropriate. (37 CFR 1.28(b))

I hereby declare that all statements made herein of my own knowledge are true, and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code, and that such willful false statements may jeopardize the validity of the application, any patent issuing thereon, or any patent to which this verified statement is directed.

NAME OF PERSON SIGNING:	Craig S, Bazzani
TITLE IN ORGANIZATION:	Comptroller and Vice President for Business and Finance
address of person signing,	352 Henry Admin. Bldg., 506 S. Wright St., Urbana, IL 6180
SIGNATURE Can Sayan	DATE 3/1/60
E-IDATA/WP60/1201/63407/SMALL DE	. • • •